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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/817,381	04/01/2004	Yongli Huang	60849-8011.US01	2603
22918 .7590 11/26/2007 PERKINS COIE LLP			EXAMINER	
P.O. BOX 2168			JAWORSKI, FRANCIS J	
MENLO PARK	K, CA 94026		ART UNIT	PAPER NUMBER
			3768	
	•			
			MAIL DATE	DELIVERY MODE
			11/26/2007	PAPER

Please find below and/or attached an Office communication concerning this application or proceeding.

The time period for reply, if any, is set in the attached communication.

	Application No.	Applicant(s)	
•	10/817,381	HUANG ET AL.	
Office Action Summary	Examiner	Art Unit	
	Jaworski Francis J.	3768	
The MAILING DATE of this communication ap Period for Reply	ppears on the cover sheet w	ith the correspondence	address
A SHORTENED STATUTORY PERIOD FOR REP WHICHEVER IS LONGER, FROM THE MAILING I  - Extensions of time may be available under the provisions of 37 CFR 1 after SIX (6) MONTHS from the mailing date of this communication.  - If NO period for reply is specified above, the maximum statutory period - Failure to reply within the set or extended period for reply will, by statu Any reply received by the Office later than three months after the maili earned patent term adjustment. See 37 CFR 1.704(b).	DATE OF THIS COMMUNIO .136(a). In no event, however, may a red d will apply and will expire SIX (6) MON tote, cause the application to become AE	CATION. reply be timely filed ITHS from the mailing date of this BANDONED (35 U.S.C. § 133).	
Status			
1) Responsive to communication(s) filed on 24	August 2007		
<u> </u>	is action is non-final.		
3) Since this application is in condition for allow		ters prosecution as to t	he merits is
closed in accordance with the practice under			no monto la
Disposition of Claims		,	
·			
4) Claim(s) 1 - 17 is/are pending in the application			
4a) Of the above claim(s) is/are withdra	awn from consideration.		
5) Claim(s) is/are allowed.			
6) Claim(s) 1 - 17 is/are rejected.			
7) Claim(s) is/are objected to.			
8) Claim(s) are subject to restriction and/	or election requirement.		
Application Papers			
9)☐ The specification is objected to by the Examir	ier.		
10) ☐ The drawing(s) filed on is/are: a) ☐ ac	cepted or b) objected to	by the Examiner.	
Applicant may not request that any objection to the	e drawing(s) be held in abeyar	nce. See 37 CFR 1.85(a).	
Replacement drawing sheet(s) including the corre	ction is required if the drawing	(s) is objected to. See 37	CFR 1.121(d).
11) The oath or declaration is objected to by the E	Examiner. Note the attached	d Office Action or form I	PTO-152.
Priority under 35 U.S.C. § 119			
12) Acknowledgment is made of a claim for foreig	ın priority under 35 U.S.C. §	§ 119(a)-(d) or (f).	
a) ☐ All b) ☐ Some * c) ☐ None of:			
1. Certified copies of the priority documer			
2. Certified copies of the priority documer			
3. Copies of the certified copies of the pri	=	received in this Nation	al Stage
application from the International Bure	, , , , , , , , , , , , , , , , , , , ,		
* See the attached detailed Office action for a lis	st of the certified copies not	received.	
Attachment(s)	" <b>.</b>		
1) Motice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948)		Summary (PTO-413) s)/Mail Date	
3) Information Disclosure Statement(s) (PTO/SB/08)	5) 🔲 Notice of I	nformal Patent Application	
Paper No(s)/Mail Date	6) 🔲 Other:	<u>_</u> .	

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## **DETAILED ACTION**

The finality of the previous office action has been WITHDRAWN in order to consider a newly uncovered reference, US6558330 to Ayter et al.

Parenthesized numerals following the rejection argument identify the specific claim or claims being addressed.

## Claim Rejections - 35 USC § 102/103

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.

Claims 1 – 17 are rejected under 35 U.S.C. 102(e) as anticipated by or, in the alternative, under 35 U.S.C. 103(a) as obvious over Ayter et al (US6558330, newly of record) in the latter case alone or further in view of Fraser (US6328697).

Ayter et al suggests that the cMUT cavity defined by support electrode 16 and membrane electrode 16 and insulating substrate 12 which comprises the walls of the cMUT well may be partially filled by an area of insulating material 40 which may also be characterized as a 'post' insofar as applicants note per the amendment response filed on July 7, 2006 page 8 top portion that 'area or post' is not constrained to any shape regularity or particular cross-section, and therefore the solid elastomeric or polymer

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variant described in col. 3 lines 22 – 33 would be either an area or post, the latter in the sense of 100% fill of the cMUT chamber up to the fractional fill height desired. [An analogy would be that a support post is also a post within tamped ground and therefore occupying 100% of its containment chamber as well in air where it stands isolated with free space surroundment.] In Ayter et al., the stated purpose is electrical isolation: Charge accumulation prevention would inherently follow intrinsic to the nature of plate capacitance insofar as the electrostatic attraction forces would gradate based upon the inwardly arched membrane electrode geometry and be limited by bottoming against this insulation portion 40, and therefore the structure shown by Ayter et al would function to provide both insulation and charge pooling.

In the alternative, if one may argue that claim 1 and additional independent claims are unmet by Ayter et al alone under any interpretation since charge and its manner of accumulation and distribution and factors which affect this are undiscussed, then it would nonetheless have been obvious in view of Fraser Figs 2 and 3 and col. 3 lines 28 – 62 that under routine operational conditions for an ultrasound cMUT, an applied DC bias voltage will create an electrostatic force so as to draw the membrane electrode towards the lower support electrode and therefore charge will concentrate in the diaphragm's center and device sensitivity to an impressed or returning echo AC voltage for (drum vibrational) transmission and reception will increase, albeit without the Fraser improvement proposal, such increasing sensitivity carries risk of contact collapse and shorting. Hence insulation layer 40 by providing a support under the membrane electrode 'roof' will act to limit the membrane deflection under voltage bias

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that would otherwise cause the membrane to fully deflect and approach the support electrode with attendant concentration of charge where the plate electrodes are near-touching, and so element 40 would 'minimize the accumulation of charge'. (Claims 1,5/1,6/5/1,7,9/7,10/9/7,15-17).

Ayter et al fabricates both the membrane support portion of electrode 16 (upper) and the support electrode 16 from silicon; Fraser notes that the insulating support such as 16 which forms the periphery of the cMUT chamber or well may be formed of silicon oxide or silicon nitride hence these are evidenced to be conventional cell constituent components when the latter combinational rejection applies. Otherwise the insulation and charge/ion accumulation arguments supra apply. (Claims 2,5/2,6/5/2, 8,9/8,10/9/8).

Noting that the Ayter et al implementation of insulating material 40 may be a partial or a full filling of the chamber (respective col. 3 portions line 35 and 22), in the case of partial filling the support electrode 'carries' the filler whereas in the case of full filling either the membrane or the support electrode may be said to 'carry' the filler in the sense of abutting containment depending on how the device is oriented. Similarly the filler may be said to be 'formed' on the electrode components since the net being that the filler assumes the shape of and abuts one or more of these, the manufacture step(s) being non-limiting on the structure (Claims 3 - 4/1 – 2,11-12/7-8).

In Ayter et al, the durability which is so provided by a filler in its partial or full-fill shape then incorporates into the optimized frequency responses of Fig. 3. (Claim 13/7-8,-14/13/7-8).

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Response to Arguments

Claims are considered to be in a clear and concise format. However the

uncovering and review of Ayter et al has resulted in a reasonable interpretation thereof

as a teaching of using a solid partial of full-space filler within the cMUT cell as an area

or a post serving to limit membrane electrode travel towards the support electrode

under application of bias voltage and/or information excursion voltage at ultrasound

frequencies, thereby serving to insulate against contact breakdown and pooling of

charge that would otherwise occur on the electrodes in the proximated portion of the

drum.

This action is NOT made final however the case should be prepared for final

action.

Any inquiry concerning this communication should be directed to Jaworski

Francis J. at telephone number 571-272-4738.

FJJ:fji

11/21/07

Francis Jalaworski Primary Exeminer